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JUN 01 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. . . . . 10/072,415  
Filing Date . . . . . February 5, 2002  
Inventor . . . . . Ji Ung Lee et al.  
Assignee . . . . . Micron Technology, Inc.  
Group Art Unit . . . . . 2891  
Examiner . . . . . Steven J. Fulk  
Confirmation No. . . . . 5182  
Customer No. . . . . 021567  
Attorney's Docket No. . . . . MI30-068  
Title: Field Effect Transistor Fabrication Methods, Field Emission Device Fabrication  
Methods, and Field Emission Device Operational Methods

RESPONSE TO FEBRUARY 1, 2006 OFFICE ACTION

To: Mail Stop Amendment  
Assistant Commissioner for Patents  
P.O. Box 1450  
Alexandria VA 22313-1450

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)  
Wells, St. John, P.S.  
601 W. First Avenue, Suite 1300  
Spokane, WA 99201-3828

Sir:

Responsive to the Office Action dated February 1, 2006, Applicants amend and  
remark as follows:

AMENDMENTS